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- Three Differential Transceivers in One Package
- Signaling Rates[†] Up to 30 Mbps
- Low Power and High Speed
- Designed for TIA/EIA-485, TIA/EIA-422, ISO 8482, and ANSI X3.277 (HVD SCSI Fast-20) Applications
- Common-Mode Bus Voltage Range -7 V to 12 V
- ESD Protection on Bus Terminals Exceeds 12 kV
- Driver Output Current up to ±60 mA
- Thermal Shutdown Protection
- Driver Positive and Negative Current Limiting
- Power-Up, Power-Down Glitch-Free Operation
- Pin-Compatible With the SN75ALS170
- Available in Shrink Small-Outline Package

description

The SN65LBC170 and SN75LBC170 are monolithic integrated circuits designed for bidirectional data communication on multipoint bus-transmission lines. Potential applications include serial or parallel data transmission, cabled peripheral buses with twin axial, ribbon, or twisted-pair cabling. These devices are suitable for FAST-20 SCSI and can transmit or receive data pulses as short as 25 ns, with skew less than 3 ns.

These devices combine three 3-state differential line drivers and three differential input line receivers, all of which operate from a single 5-V power supply.

The driver differential outputs and the receiver differential inputs are connected internally to form three differential input/output (I/O) bus ports that are designed to offer minimum loading to the bus whenever the driver is disabled or $V_{CC} = 0$. These ports feature a wide common-mode voltage range making the device suitable for party-line applications over long cable runs.

SN75LBC170DB (marked as BL170)
(TOP VIEW)

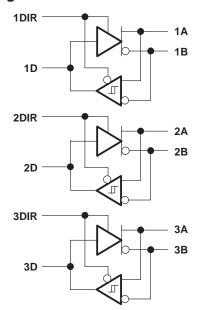
1D [[1	16]] 1B
1DIR [[2	15]] 1A
NC [[3	14]] NC
GND [[4	13	∐Vcc
2D [5	12]] 2B
2DIR [6	11]] 2A
3D [7	10]] 3B
3DIR [8	9]] 3A
			I

SN65LBC170DW (marked as 65LBC170) SN75LBC170DW (marked as 75LBC170)

	(TOF	P VIEW)
1D [[1	20	∏ 1B
1DIR []	2	19	∏ 1A
NC []	3	18	∏ NC
GND [[4	17	∏ NС
NC []	5	16	∏ V _{СС}
2D []	6	15	∏ 2В
2DIR [[7	14]] 2А
NC [[8	13]] 3В
3D []	9	12]] 3А
3DIR [10	11]] NC

NC – No internal connection

logic diagram





Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

[†]The signaling rate of a line is the number of voltage transitions that are made per second expressed in the units bps (bits per second).

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.



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description (continued)

The driver's active-high enable and the receiver's active-low enable are tied together internally and provide a direction input for each driver/receiver pair.

The SN75LBC170 is characterized for operation over the temperature range of 0°C to 70°C. The SN65LBC170 is characterized for operation over the temperature range of -40°C to 85°C.

AVAILABLE	OPTIONS [†]
-----------	----------------------

	PACKAGE	
TA	PLASTIC SHRINK SMALL-OUTLINE (JEDEC MO-150)	PLASTIC SMALL-OUTLINE (JEDEC MS-013)
0°C to 70°C	SN75LBC170DB	SN75LBC170DW
-40°C to 85°C	SN65LBC170DB	SN65LBC170DW

Function Tables

[†]Add R suffix for taped and reel

[†] For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.

OUTPUT

D Н

?

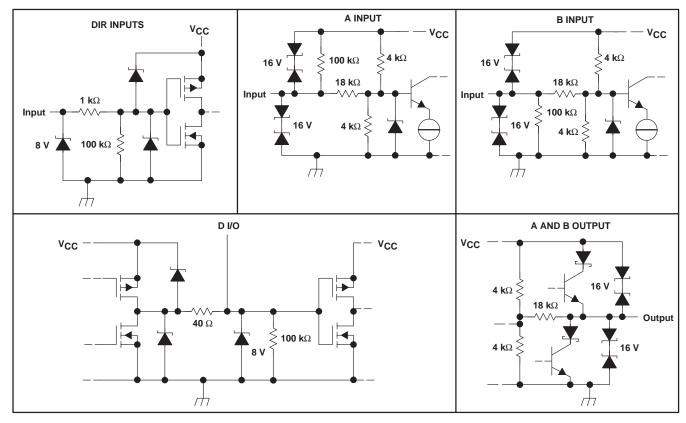
L Ζ

Н

	EACH DRIVER				EACH REC	EIVER
INPUT	ENABLE	001	OUTPUTS			ENABLE
D	DIR	Α	В		(V _A –V _B)	DIR
Н	Н	Н	L		$V_{ID} \ge 0.2 V$	L
L	Н	L	Н		$-0.2 \text{ V} < \text{V}_{\text{ID}} < 0.2 \text{ V}$	L
OPEN	Н	L	Н		$V_{ID} \le -0.2 V$	L
Х	L	Z	Ζ		Х	н
Х	OPEN	Х	Х		OPEN	L

H = high level, L = low level, X = irrelevant, Z = high impedance (off), ? = indeterminate

equivalent input and output schematic diagrams





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absolute maximum ratings[†] over operating free-air temperature range (unless otherwise noted)

Supply voltage, V _{CC} (see Note 1) –0.3 V to 6 V Voltage range at any bus I/O terminal (steady state)
Voltage input range, A and B, (transient pulse through 100 Ω , see Figure 12)
Voltage range at any D or DIR terminal – 0.5 V to V _{CC} + 0.5 V
Receiver output current, I _O ±10 mA
Electrostatic discharge: Human body model (A, B, GND) (see Note 2) 12 kV
All pins 5 kV
Charged-device model (all pins) (see Note 3) 1 kV
Continuous total power dissipation

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. All voltage values, except differential I/O bus voltages, are with respect to network ground terminal.

2. Tested in accordance with JEDEC Standard 22, Test Method A114-A.

3. Tested in accordance with JEDEC Standard 22, Test Method C101.

POWER DISSIPATION RATING TABLE

PACKAGE	T _A ≤ 25°C POWER RATING	DERATING FACTOR [‡] ABOVE T _A = 25°C	T _A = 70°C POWER RATING	T _A = 85°C POWER RATING
DB	995 mW	8.0 mW/°C	635 mW	515 mW
DW	1480 mW	11.8 mW/°C	950 mW	770 mW

[‡]This is the inverse of the junction-to-ambient thermal resistance when board-mounted and with no air flow.

recommended operating conditions

		MIN	NOM	MAX	UNIT
Supply voltage, V _{CC}		4.75	5	5.25	V
Voltage at any bus I/O terminal	А, В	-7		12	V
High-level input voltage, VIH		2		VCC	N/
Low-level input voltage, VIL	D, DIR	0		0.8	V
Differential input voltage, VID	A with respect to B	-12		12	V
	Driver	-60		60	
Output current	Receiver	-8		8	mA
	SN75LBC170	0		70	^
Operating free-air temperature, T_A	SN65LBC170	-40		85	°C



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DRIVER SECTION

electrical characteristics over recommended operating conditions

	PARAMETER		TEST CONDITIONS		MIN	TYP [†]	MAX	UNIT
VIK	Input clamp voltage	D and DIR	lj = 18 mA		-1.5	-0.7		V
VO	Open-circuit output voltage (sir	ngle-ended)	A or B, No load		0		VCC	V
			No load		3.8	4.3	VCC	
VOD(SS)	Steady-state differential output magnitude [‡]	voltage	R _L = 54 Ω,	See Figure 1	1	1.6	2.4	V
()	Thag induce i		With common-mode	loading, See Figure 2	1	1.6	2.4	
ΔV_{OD}	Change in differential output ve magnitude, VOD(H) - VOD				-0.2		0.2	V
V _{OC(SS)}	Steady-state common-mode	output voltage	R _L = 54 Ω, C _I = 50 pF	See Figure 1	2	2.4	2.8	
ΔVOC(SS)	Change in steady-state community voltage ($V_{OC(H)} - V_{OC(L)}$)	on-mode output	- о <u>г</u> – 30 рг		-0.2		0.2	V
lj	Input current		D, DIR		-100		100	μΑ
IO	Output current with power off	:	$V_{CC} = 0 V,$	$V_{O} = -7 V$ to 12 V	-700		900	μA
IOS	Short-circuit output current		$V_{O} = -7 V$ to 12 V,	See Figure 7	-250		250	mA
ICC	Supply current (driver enable	d)	D at 0 V or V _{CC} ,	DIR at V _{CC} , No load		14	20	mA

[†] All typical values are at $V_{CC} = 5$ V and $T_A = 25^{\circ}C$.

[‡] The minimum V_{OD} may not fully comply with TIA/EIA-485-A at operating temperatures below 0°C. System designers should take the possibly lower output signal into account in determining the maximum signal-transmission distance.

switching characteristics over recommended operating conditions

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
^t PLH	Differential output propagation delay, low-to high		4	8.5	12	
^t PHL	Differential output propagation delay, high-to-low	7	4	8.5	11	
t _r	Differential output rise time	7	3	7.5	11	
t _f	Differential output fall time	$R_L = 54 \Omega$, $C_L = 50 pF$, See Figure 3	3	7.5	11	ns
^t sk(p)	Pulse skew (tpLH - tpHL)				2	
tsk(o)	Output skew§	7			1.5	
^t sk(pp)	Part-to-part skew¶	7			2	
^t PLH	Differential output propagation delay, low-to high	See Figure 4, (HVD SCSI double-terminated load)	3	7	10	
^t PHL	Differential output propagation delay, high-to-low		3	7.5	10	
t _r	Differential output rise time		3	7.5	12	
tf	Differential output fall time		3	7.5	12	ns
^t sk(p)	Pulse skew (tpLH - tpHL)				3	
^t sk(o)	Output skew§	7			1.5	
^t sk(pp)	Part-to-part skew [¶]	7			2.5	
^t PZH	Output enable time to high level	Con Firmer F		15	25	
^t PHZ	Output disable time from high level	See Figure 5		18	25	ns
^t PZL	Output enable time to low level		1	10	25	
^t PLZ	Output disable time from low level	See Figure 6		17	25	ns

 Output skew (t_{Sk(O)}) is the magnitude of the time delay difference between the outputs of a single device with all of the inputs connected together. Part-to-part skew (t_{Sk(pp)}) is the magnitude of the difference in propagation delay times between any specified terminals of two devices when both devices operate with the same input signals, the same supply voltages, at the same temperature, and have identical packages and test circuits.



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RECEIVER SECTION

electrical characteristics over recommended operating conditions

	PARAMETER	TEST CONDITIONS		MIN	TYP†	MAX	UNIT
V_{IT+}	Positive-going differential input voltage threshold	See Figure 8				0.2	
V_{IT-}	Negative-going differential input voltage threshold			-0.2			V
V _{hys}	Hysteresis voltage (V _{IT+} – V _{IT–})				40		mV
VOH	High-level output voltage	V_{ID} = 200 mV, I_{OH} = -8 mA, See Figure 8		4	4.7	VCC	N
VOL	Low-level output voltage	$V_{ID} = -200 \text{ mV}, I_{OL} = -8 \text{ mA}, \text{ See Figure 8}$		0	0.2	0.4	V
	I have been dealers and	Others is not a bit	Vj = 12 V			0.9	
1	Line input current	Other input = 0 V	$V_{I} = -7 V$	-0.7			mA
RI	Input resistance	А, В		12			kΩ
ICC	Supply current (receiver enabled)	A, B, D, and DIR ope	en			16	mA

[†] All typical values are at $V_{CC} = 5$ V and $T_A = 25^{\circ}C$.

switching characteristics over recommended operating conditions

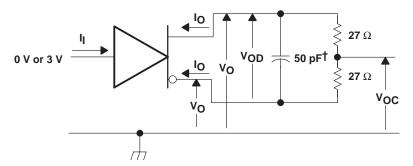
	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
t _{PLH}	Propagation delay time, low-to-high level output		7		16	ns
^t PHL	Propagation delay time, high-to-low level output		7		16	ns
t _r	Receiver output rise time	See Figure 9		1.3	3	ns
t _f	Receiver output fall time			1.3	3	ns
^t PZH	Receiver output enable time to high level			26	40	
^t PHZ	Receiver output disable time from high level	See Figure 10			40	ns
^t PZL	Receiver output enable time to low level			29	40	
^t PLZ	Receiver output enable time to high level	See Figure 11			40	ns
^t sk(p)	Pulse skew (tpLH – tpHL)				2	ns
^t sk(o)	Output skew‡				1.5	ns
^t sk(pp)	Part-to-part skew§				3	ns

[‡]Output skew ($t_{sk(o)}$) is the magnitude of the time delay difference between the outputs of a single device with all of the inputs connected together. § Part-to-part skew ($t_{sk(pp)}$) is the magnitude of the difference in propagation delay times between any specified terminals of two devices when both devices operate with the same input signals, the same supply voltages, at the same temperature, and have identical packages and test circuits.



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PARAMETER MEASUREMENT INFORMATION



[†] Includes probe and jig capacitance

Figure 1. Driver Test Circuit, V_{OD} and V_{OC} Without Common-Mode Loading

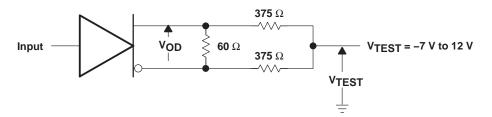
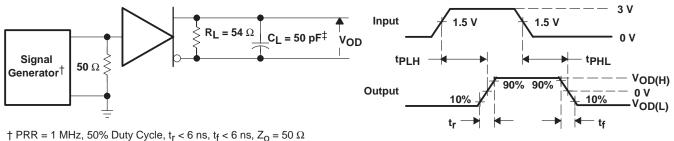


Figure 2. Driver Test Circuit, V_{OD} With Common-Mode Loading



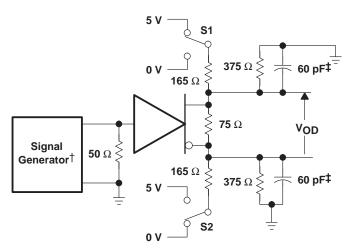
‡ Includes probe and jig capacitance

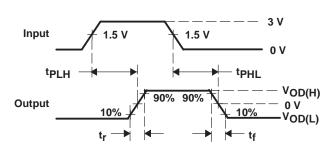
Figure 3. Driver Switching Test Circuit and Waveforms, 485-Loading



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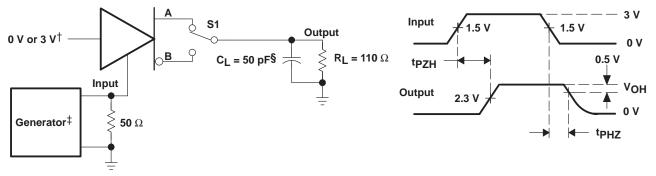
PARAMETER MEASUREMENT INFORMATION





† PRR = 1 MHz, 50% Duty Cycle, t_r < 6 ns, t_f < 6 ns, Z_0 = 50 Ω ‡ Includes probe and jig capacitance

Figure 4. Driver Switching Test Circuit and Waveforms, HVD SCSI-Loading (double terminated)

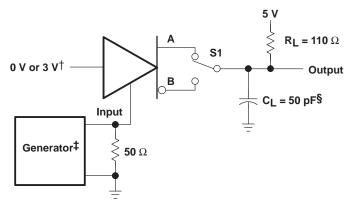


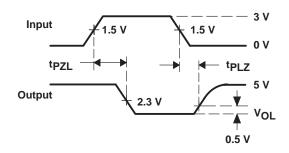
† 3 V if testing A output, 0 V if testing B output

 \ddagger PRR = 1 MHz, 50% Duty Cycle, t_f < 6 ns, t_f < 6 ns, Z₀ = 50 Ω

§ Includes probe and jig capacitance

Figure 5. Driver Enable/Disable Test, High Output





† 0 V if testing A output, 3 V if testing B output

 \ddagger PRR = 1 MHz, 50% Duty Cycle, t_f < 6 ns, t_f < 6 ns, Z₀ = 50 Ω

§ Includes probe and jig capacitance

Figure 6. Driver Enable/Disable Test, Low Output



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PARAMETER MEASUREMENT INFORMATION

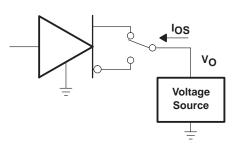
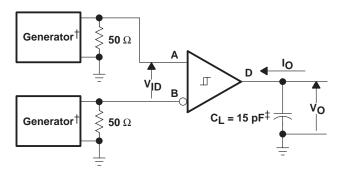


Figure 7. Driver Short-Circuit Test



 \dagger PRR = 1 MHz, 50% Duty Cycle, t_{f} < 6 ns, t_{f} < 6 ns, Z_{O} = 50 Ω \ddagger Includes probe and jig capacitance

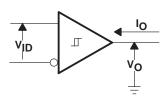
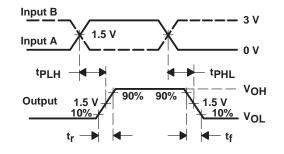


Figure 8. Receiver DC Parameters



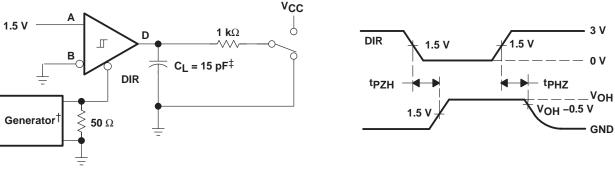


Figure 9. Receiver Switching Test Circuit and Waveforms

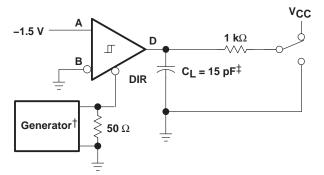
† PRR = 1 MHz, 50% Duty Cycle, t_r < 6 ns, t_f < 6 ns, Z_0 = 50 Ω ‡ Includes probe and jig capacitance

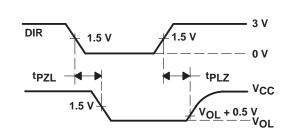




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PARAMETER MEASUREMENT INFORMATION





 \dagger PRR = 1 MHz, 50% Duty Cycle, t_{f} < 6 ns, t_{f} < 6 ns, Z_{O} = 50 Ω \ddagger Includes probe and jig capacitance

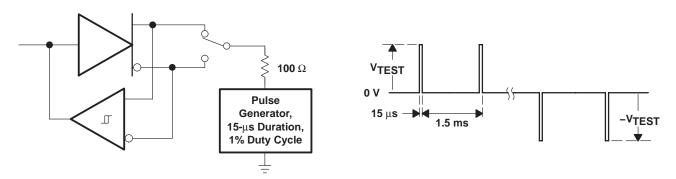
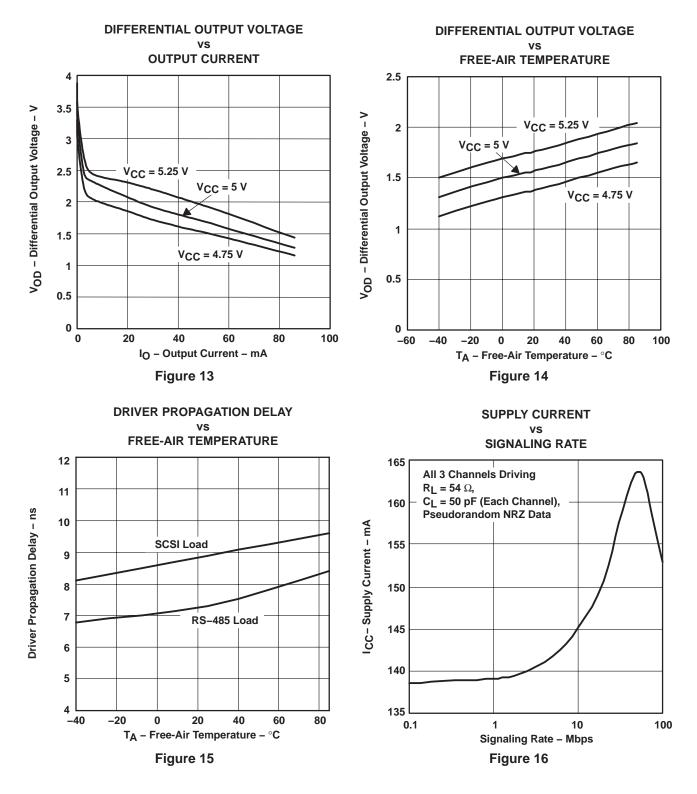




Figure 12. Test Circuit and Waveform, Transient Over Voltage Test

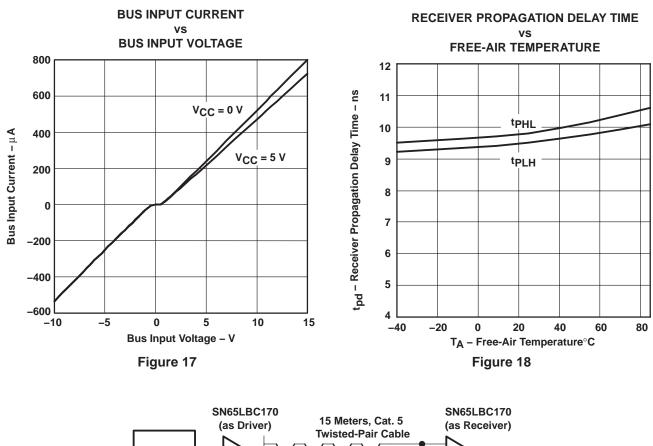


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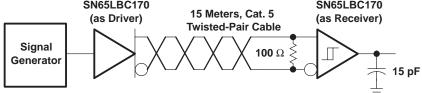
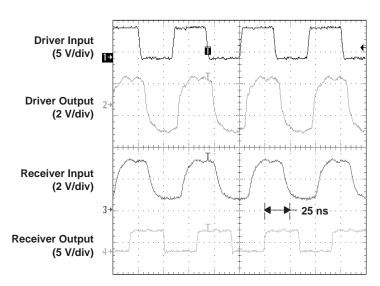


Figure 19. Circuit Diagram for Signaling Characteristics



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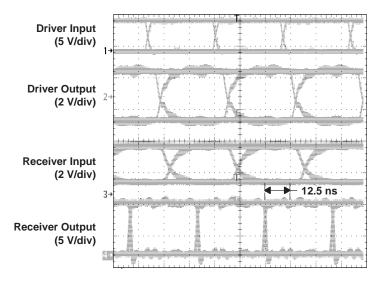
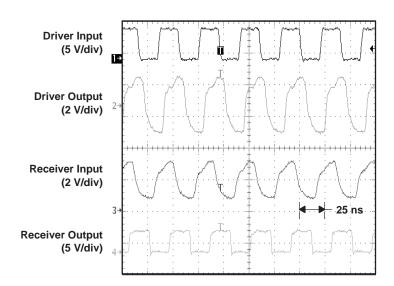


Figure 21. Eye Patterns, Pseudorandom Data at 30 Mbps



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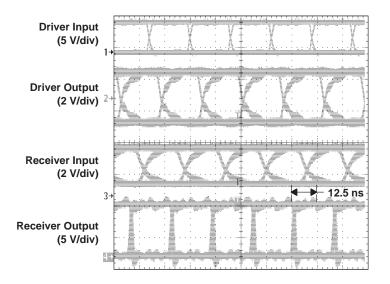


Figure 23. Eye Patterns, Pseudorandom Data at 50 Mbps



24-Jan-2013

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Top-Side Markings	Samples
SN65LBC170DB	ACTIVE	SSOP	DB	16	80	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	BL170	Samples
SN65LBC170DBG4	ACTIVE	SSOP	DB	16	80	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	BL170	Samples
SN65LBC170DBR	ACTIVE	SSOP	DB	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	BL170	Samples
SN65LBC170DBRG4	ACTIVE	SSOP	DB	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	BL170	Samples
SN65LBC170DW	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	65LBC170	Samples
SN65LBC170DWG4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	65LBC170	Samples
SN75LBC170DB	ACTIVE	SSOP	DB	16	80	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	LB170	Samples
SN75LBC170DBG4	ACTIVE	SSOP	DB	16	80	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	LB170	Samples
SN75LBC170DBR	ACTIVE	SSOP	DB	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	LB170	Samples
SN75LBC170DBRG4	ACTIVE	SSOP	DB	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	LB170	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)



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24-Jan-2013

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ Only one of markings shown within the brackets will appear on the physical device.

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PACKAGE MATERIALS INFORMATION

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Texas Instruments

TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are r	nominal											
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN65LBC170E	BR SSOP	DB	16	2000	330.0	16.4	8.2	6.6	2.5	12.0	16.0	Q1
SN75LBC170D	BR SSOP	DB	16	2000	330.0	16.4	8.2	6.6	2.5	12.0	16.0	Q1

TEXAS INSTRUMENTS

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PACKAGE MATERIALS INFORMATION

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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN65LBC170DBR	SSOP	DB	16	2000	367.0	367.0	38.0
SN75LBC170DBR	SSOP	DB	16	2000	367.0	367.0	38.0

DW (R-PDSO-G20)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters). Dimensioning and tolerancing per ASME Y14.5M-1994.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).

D. Falls within JEDEC MS-013 variation AC.



LAND PATTERN DATA



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Refer to IPC7351 for alternate board design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



MECHANICAL DATA

MSSO002E - JANUARY 1995 - REVISED DECEMBER 2001

DB (R-PDSO-G**)

PLASTIC SMALL-OUTLINE

28 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.
- D. Falls within JEDEC MO-150



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